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April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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CR03AM-12

Thyristor

Low Power Use

REJ03G0352-0200

Rev.2.00

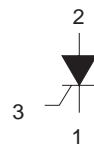
Mar.01.2005

Features

- $I_{T(AV)}$: 0.3 A
- V_{DRM} : 600 V
- I_{GT} : 100 μ A
- Non-Insulated Type
- Glass Passivation Type

Outline

PRSS0003EA-A
(Package name:TO-92)



1. Cathode
2. Anode
3. Gate

Applications

Leakage protector, timer, and gas igniter

Maximum Ratings

Parameter	Symbol	Voltage class	Unit
		12	
Repetitive peak reverse voltage	V_{RRM}	600	V
Non-repetitive peak reverse voltage	V_{RSM}	800	V
DC reverse voltage	$V_{R(DC)}$	480	V
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	600	V
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	800	V
DC off-state voltage ^{Note1}	$V_{D(DC)}$	480	V

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I_T (RMS)	0.47	A	
Average on-state current	I_T (AV)	0.3	A	Commercial frequency, sine half wave 180° conduction, $T_a = 47^\circ\text{C}$
Surge on-state current	I_{TSM}	20	A	60Hz sine half wave 1 full cycle, peak value, non-repetitive
I^2t for fusing	I^2t	1.6	A^2s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	P_{GM}	0.5	W	
Average gate power dissipation	P_G (AV)	0.1	W	
Peak gate forward voltage	V_{FGM}	6	V	
Peak gate reverse voltage	V_{RGM}	6	V	
Peak gate forward current	I_{FGM}	0.3	A	
Junction temperature	T_j	- 40 to +110	$^\circ\text{C}$	
Storage temperature	T_{stg}	- 40 to +125	$^\circ\text{C}$	
Mass	—	0.23	g	Typical value

Notes: 1. With gate to cathode resistance $R_{GK} = 1\text{ k}\Omega$.

Electrical Characteristics

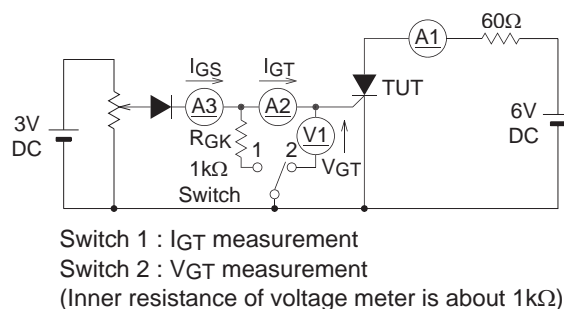
Parameter	Symbol	Min.	Typ.	Max.	Unit	Test conditions
Repetitive peak reverse current	I_{RRM}	—	—	0.1	mA	$T_j = 110^\circ\text{C}$, V_{RRM} applied
Repetitive peak off-state current	I_{DRM}	—	—	0.1	mA	$T_j = 110^\circ\text{C}$, V_{DRM} applied, $R_{GK} = 1\text{ k}\Omega$
On-state voltage	V_{TM}	—	—	1.8	V	$T_a = 25^\circ\text{C}$, $I_{TM} = 4\text{ A}$, instantaneous value
Gate trigger voltage	V_{GT}	—	—	0.8	V	$T_j = 25^\circ\text{C}$, $V_D = 6\text{ V}$, $I_T = 0.1\text{ A}$ ^{Note3}
Gate non-trigger voltage	V_{GD}	0.2	—	—	V	$T_j = 110^\circ\text{C}$, $V_D = 1/2 V_{DRM}$, $R_{GK} = 1\text{ k}\Omega$
Gate trigger current	I_{GT}	1	—	100 ^{Note2}	μA	$T_j = 25^\circ\text{C}$, $V_D = 6\text{ V}$, $I_T = 0.1\text{ A}$ ^{Note3}
Holding current	I_H	—	1.5	3	mA	$T_j = 25^\circ\text{C}$, $V_D = 12\text{ V}$, $R_{GK} = 1\text{ k}\Omega$
Thermal resistance	$R_{th(j-a)}$	—	—	180	$^\circ\text{C/W}$	Junction to ambient

Notes: 2. If special values of I_{GT} are required, choose item D or E from those listed in the table below if possible.

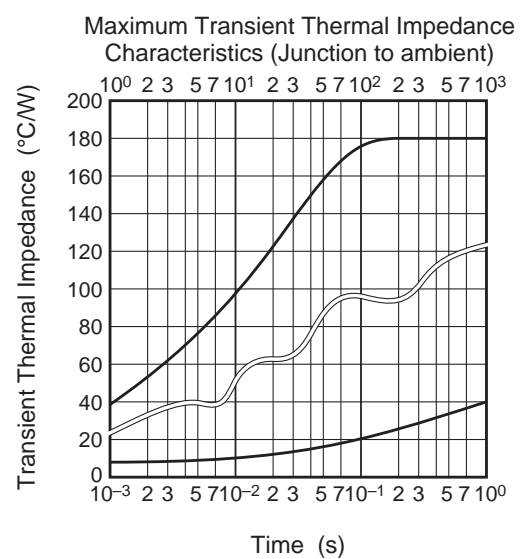
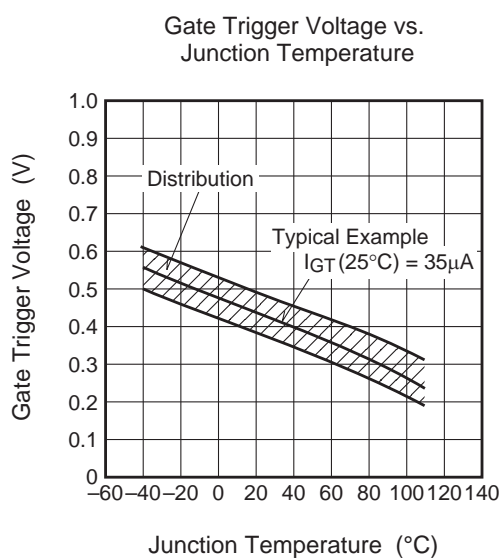
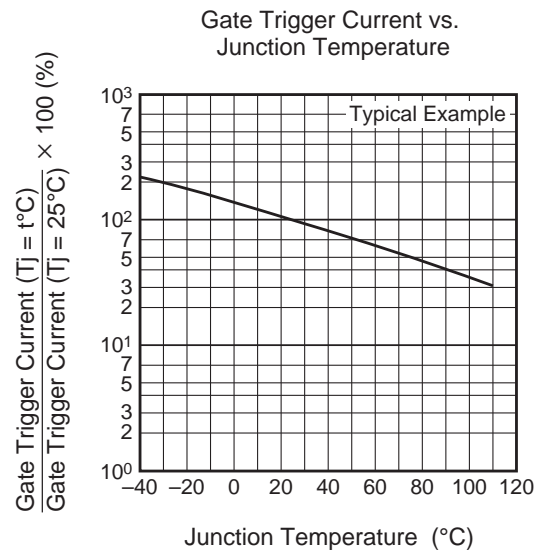
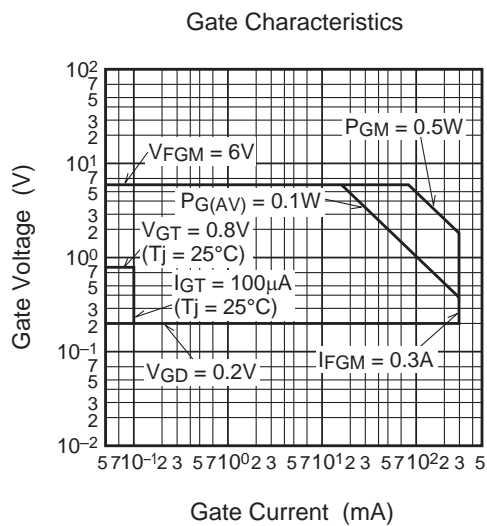
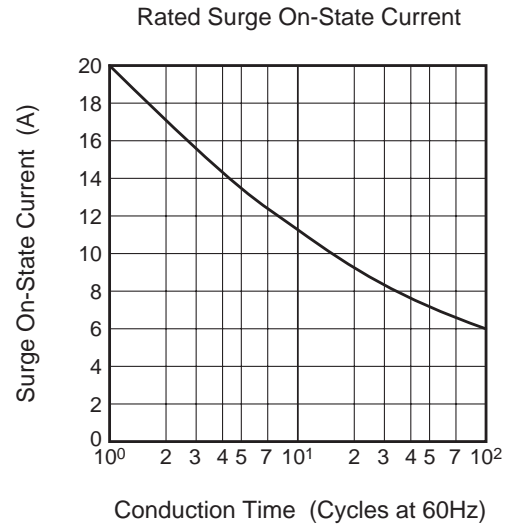
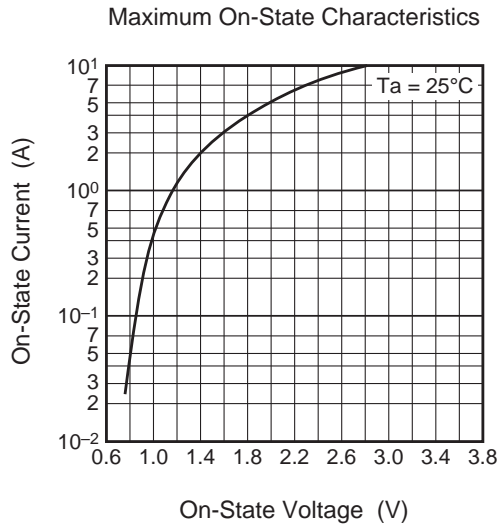
Item	A	B	C	D	E
I_{GT} (μA)	1 to 30	20 to 50	40 to 100	1 to 50	20 to 100

The above values do not include the current flowing through the $1\text{ k}\Omega$ resistance between the gate and cathode.

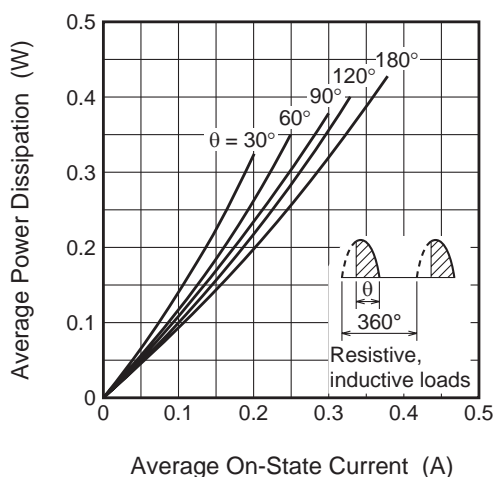
3. I_{GT} , V_{GT} measurement circuit.



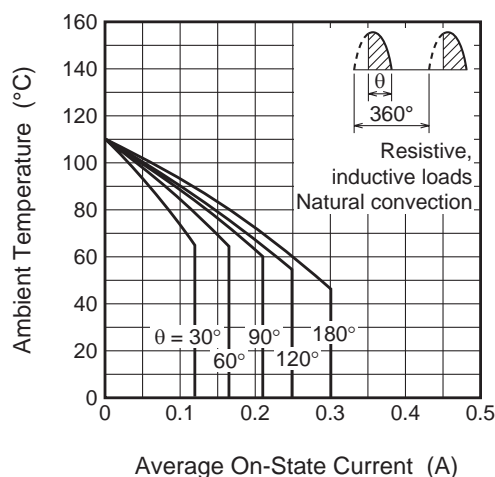
Performance Curves



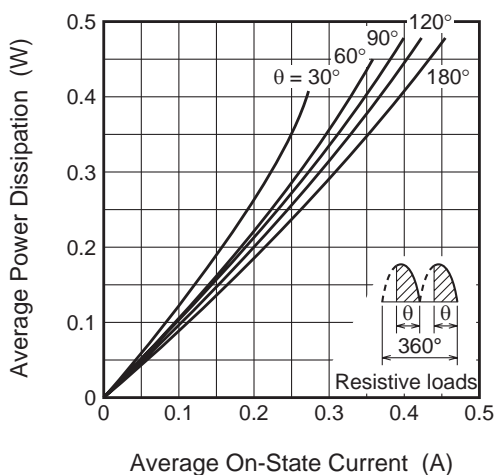
Maximum Average Power Dissipation
(Single-Phase Half Wave)



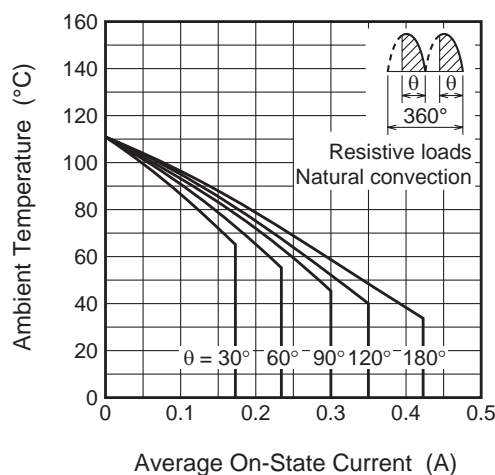
Allowable Ambient Temperature vs.
Average On-State Current
(Single-Phase Half Wave)



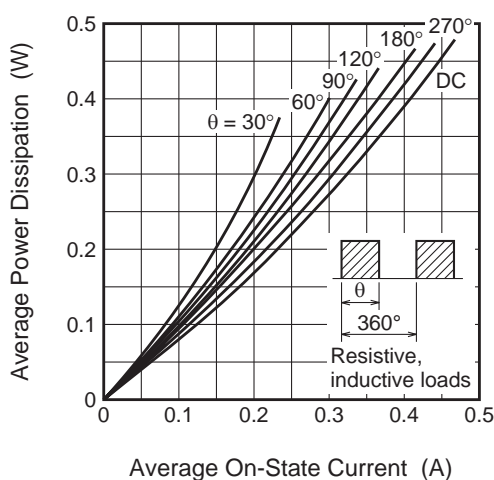
Maximum Average Power Dissipation
(Single-Phase Full Wave)



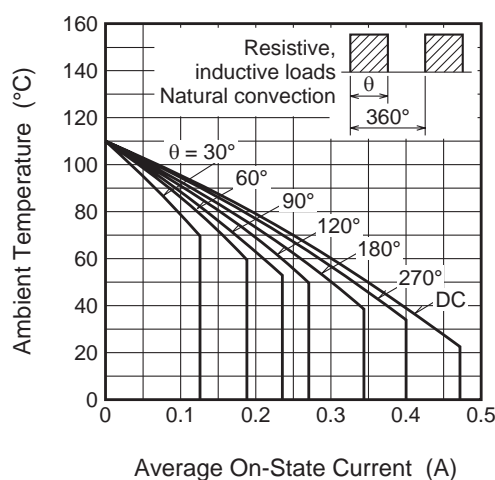
Allowable Ambient Temperature vs.
Average On-State Current
(Single-Phase Full Wave)

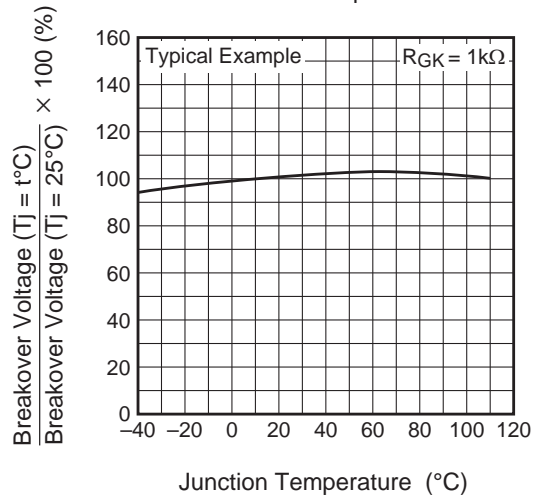
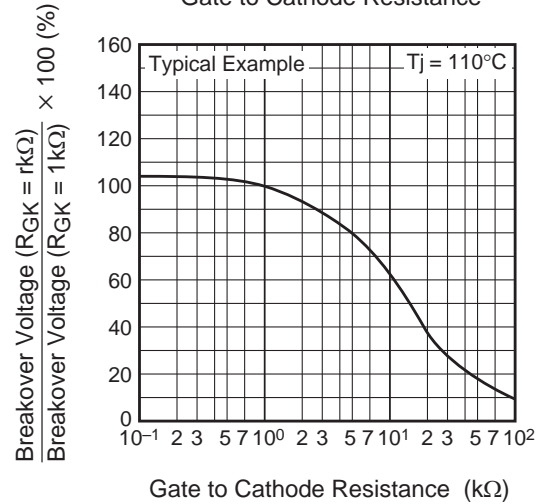
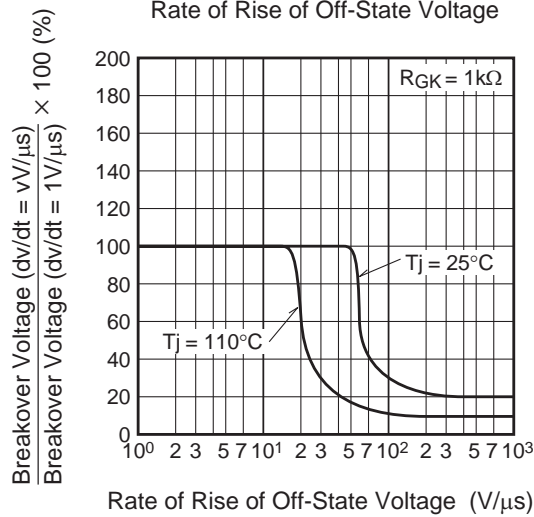
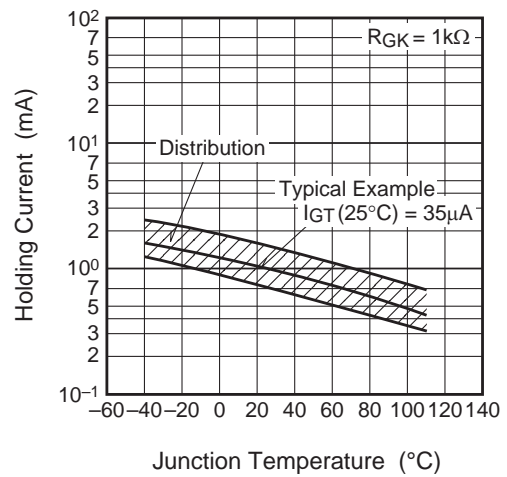
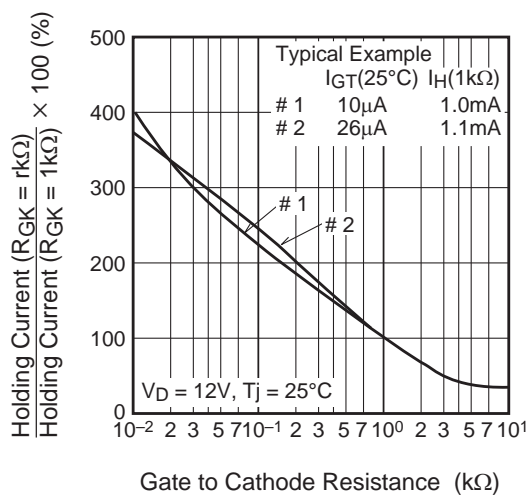
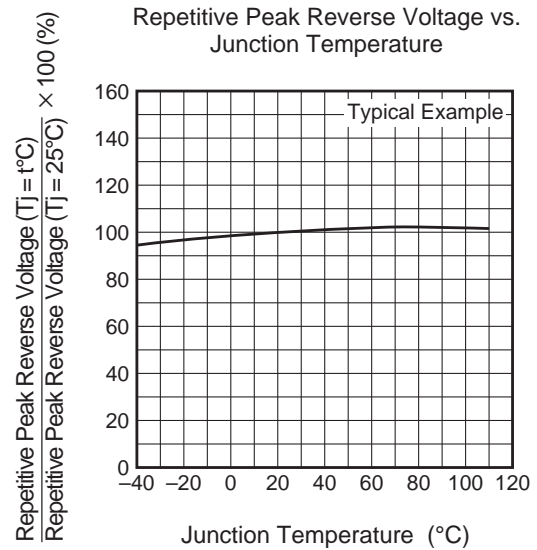


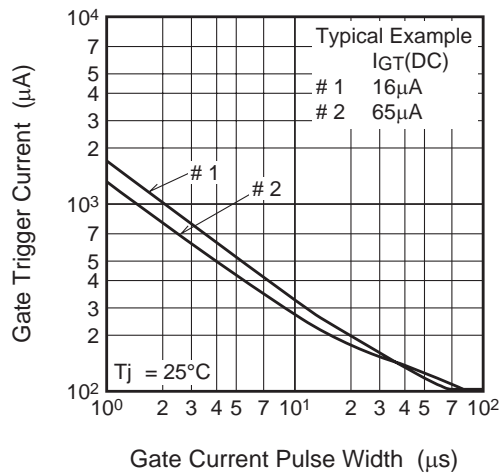
Maximum Average Power Dissipation
(Rectangular Wave)



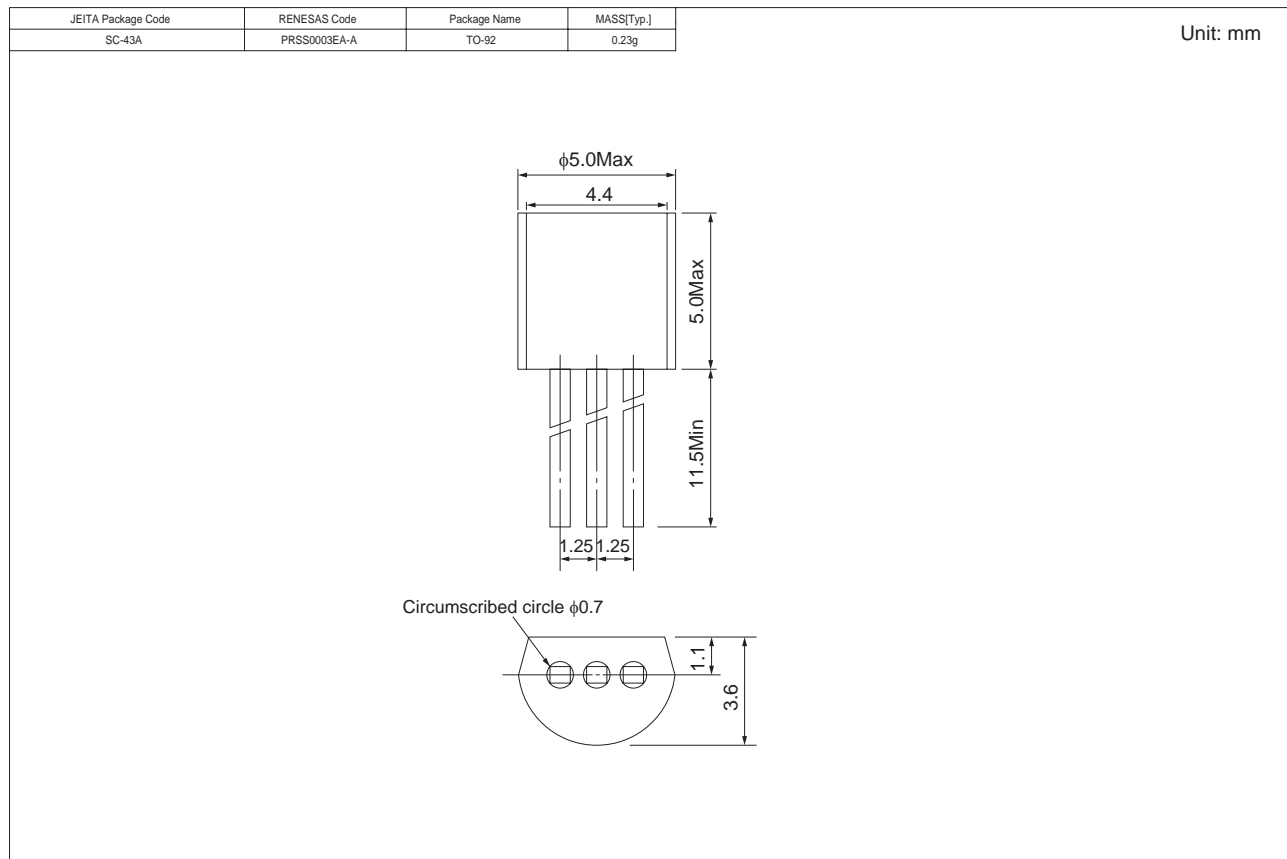
Allowable Ambient Temperature vs.
Average On-State Current
(Rectangular Wave)



Breakover Voltage vs.
Junction TemperatureBreakover Voltage vs.
Gate to Cathode ResistanceBreakover Voltage vs.
Rate of Rise of Off-State VoltageHolding Current vs.
Junction TemperatureHolding Current vs.
Gate to Cathode ResistanceRepetitive Peak Reverse Voltage vs.
Junction Temperature

Gate Trigger Current vs.
Gate Current Pulse Width

Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Straight type	Vinyl sack	500	Type name	CR03AM-12
Lead form	Vinyl sack	500	Type name – Lead forming code	CR03AM-12-A6
Form A8	Taping	2000	Type name – TB	CR03AM-12-TB

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